## NSN 5961-01-189-9373

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-189-9373 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Overall Diameter:** 0.079 inches **Component Name And Quantity:** 4 light emitting diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all light emitting diode Voltage Rating In Volts Per Characteristic: 6.0 forward voltage, dc all light emitting diode and 6.0 breakover voltage, dc all light emitting diode **Current Rating Per Characteristic:** 5.00 milliamperes source cutoff current horsepower metric all light emitting diode **Color Tone Produced Per Source:** Red semiconductor all light emitting diode **Luminous Intensity:** 0.2 millicandela all light emitting diode **Special Features:** All light emitting diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: